

# Silicon NPN Power Transistor

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 60V(Min)
- DC Current Gain-
  - : h<sub>FE</sub>= 30(Min)@ I<sub>C</sub>= 1A

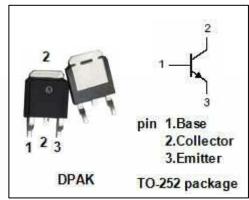
### **APPLICATIONS**

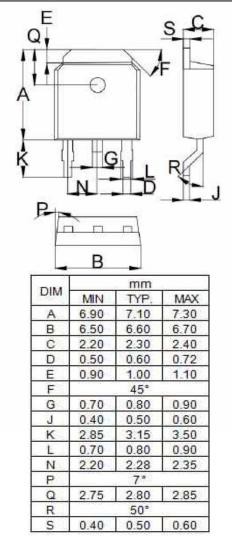
• DC-DC converter, relay drivers, lamp drivers, motor drivers, inverter



## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	8	V	
lc	Collector Current	4	Α	
Ісм	Peak collector current	6	А	
P <sub>C</sub>	Collector Power Dissipation	1.3	W	
	Collector Power Dissipation @T <sub>C</sub> = 25℃	30		
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	







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2SD1251

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.4A			1.0	V
V <sub>CEO</sub> (SUS)	Collector-Emitter Voltage	I <sub>C</sub> = 0.2A; L=25mH	60		1	٧
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 20V; I <sub>E</sub> = 0			30	uA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 8V; I <sub>C</sub> = 0			1	mA
h <sub>FE1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 3V	30		160	
h <sub>FE2</sub>	DC Current Gain	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 3V	40			

### Classification of hFE1

Туре	Q	Р	0
Range	30-60	50-100	80-150

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